

Si Phototransistor

KPT801HB

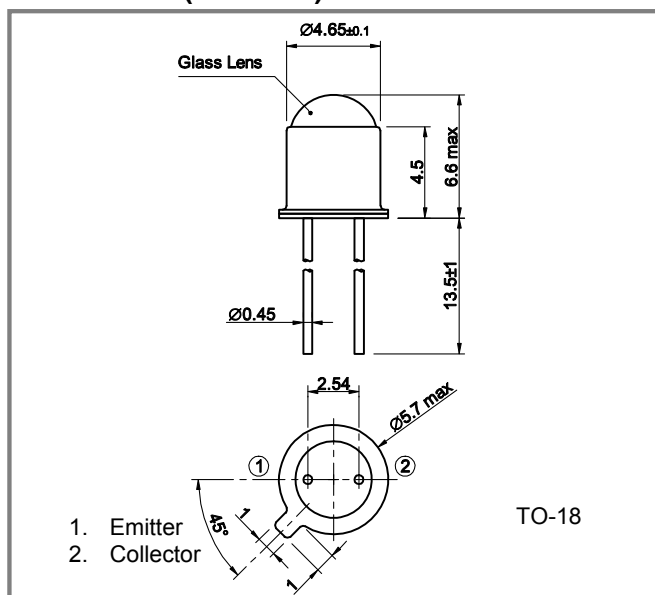
Features

- NPN phototransistor packaged in a 2 leads TO-18
- Glass lens or visible-cut black epoxy lens
- Low leak current

Applications

- Optical switches
- Optical encoders
- Photo-isolator
- Camera stroboscopes
- Infrared sensors
- Automatic control apparatus

Dimensions (unit: mm)



Absolute Maximum Ratings

Parameter	Symbol	Value	Unit	Note
Collector-emitter voltage	V_{ce0}	20	V	
Emitter-collector voltage	V_{eco}	5	V	
Collector-base voltage	V_{cbo}	-	V	
Emitter-base voltage	V_{ebo}	-	V	
Operating temperature	T_{opr}	-25 to +125	°C	Avoid dew condensation
Storage temperature	T_{stg}	-55 to +150	°C	Avoid dew condensation

Electrical and Optical Characteristics (Ta=25 °C unless otherwise noted)

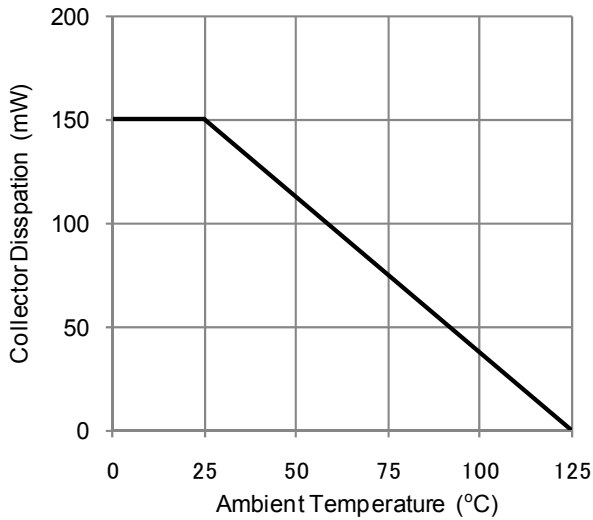
Parameter	Symbol	Min.	Typ.	Max	Unit	Test Conditions
Active area	S	0.64 x 0.64			mm ²	
Operating voltage	V_{opr}	5			V	
Sensitive wavelength	λ	700	800 (λ_p)	1000	nm	λ_p =Peak wavelength
Photocurrent	I_L	-	3	-	mA	$V_{ce} = 5V$, 100lx(@2856K)
Dark current	I_{ceo}	-	100	200	nA	$V_{ce} = 20V$
Current amplification factor	h_{FE}	600	-	-		$V_{ce} = 5V$, $I_c=2mA$
Collector-emitter saturation voltage	$V_{ce(sat)}$	-	-	0.4	V	$I_c=0.1mA$
Rise/fall time	t_r, t_f	-	5	-	μs	$V_{ce} = 5V$, $I_c=2mA, R_L=100\Omega$

Specifications are subject to change without notice.

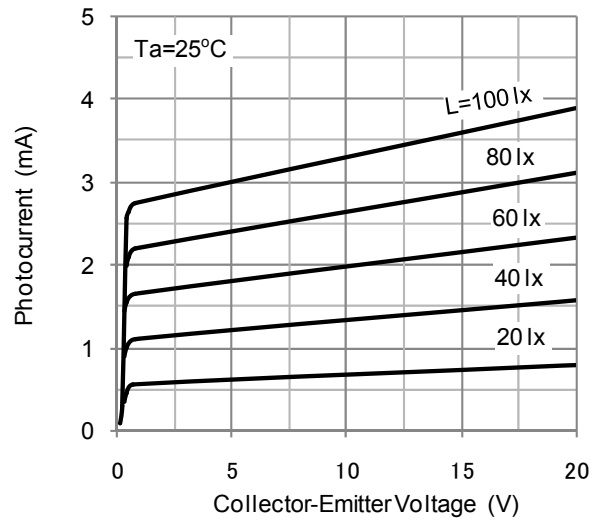
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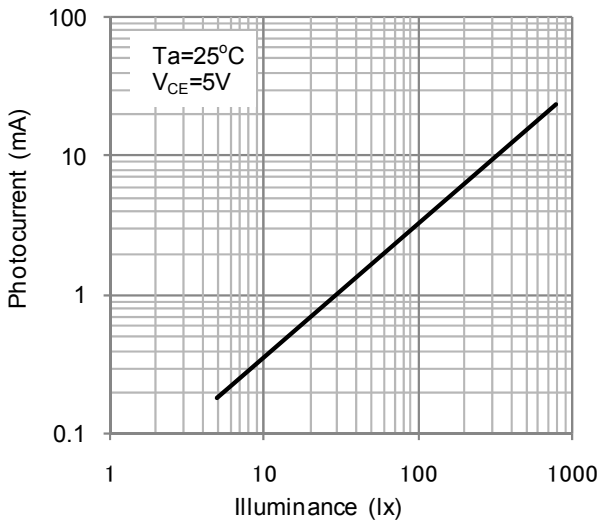
Collector Dissipation-Ambient Temperature



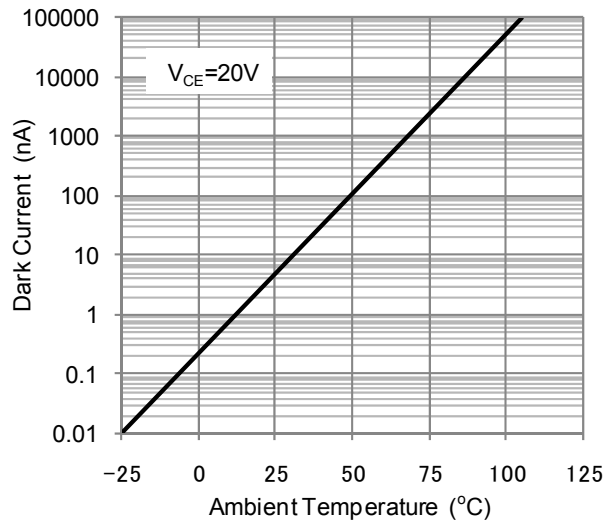
Photocurrent - Collector-Emitter Voltage



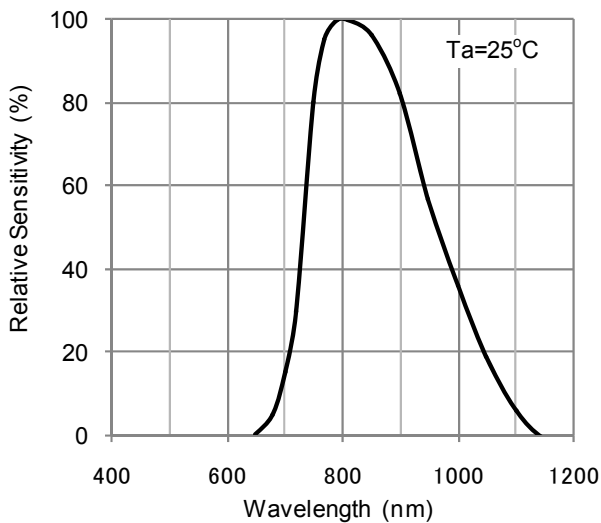
Photocurrent - Illuminance



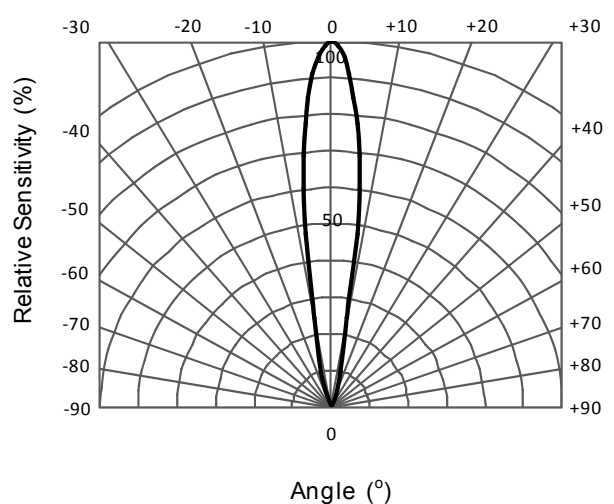
Dark Current - Ambient Temperature



Spectral Responsivity



Directivity



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Contacts:

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